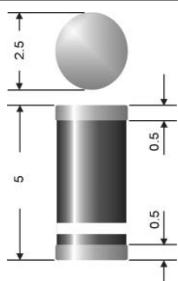


SM 4001...SM 4007



Surface mount diode

Standard silicon rectifier diodes

SM 4001...SM 4007

Forward Current: 1 A

Reverse Voltage: 50 to 1000 V

Features

- Max. solder temperature: 260°C
- Plastic material has UL classification 94V-0

Mechanical Data

- Plastic case Melf / DO-213AB
- Weight approx.: 0,12 g
- Terminals: plated terminals solderable per MIL-STD-750
- Mounting position : any
- Standard packaging: 5000 pieces per reel

1) Max. temperature of the terminals $T_T = 75^\circ\text{C}$

2) $I_F = 1 \text{ A}$, $T_j = 25^\circ\text{C}$

3) $T_A = 25^\circ\text{C}$

4) Mounted on P.C. board with 25 mm² copper pads at each terminal

Type	Polarity color band	Repetitive peak reverse voltage	Surge peak reverse voltage	Maximum forward voltage $T_j = 25^\circ\text{C}$ $I_F = 1 \text{ A}$	Maximum reverse recovery time $I_F = -1 \text{ A}$ $I_R = -1 \text{ A}$ $I_{RR} = -1 \text{ A}$ t_{rr} ns
		V_{RRM} V	V_{RSM} V	$V_F^{(2)}$ V	
SM 4001	-	50	50	1,1	-
SM 4002	-	100	100	1,1	-
SM 4003	-	200	200	1,1	-
SM 4004	-	400	400	1,1	-
SM 4005	-	600	600	1,1	-
SM 4006	-	800	800	1,1	-
SM 4007	-	1000	1000	1,1	-

Absolute Maximum Ratings

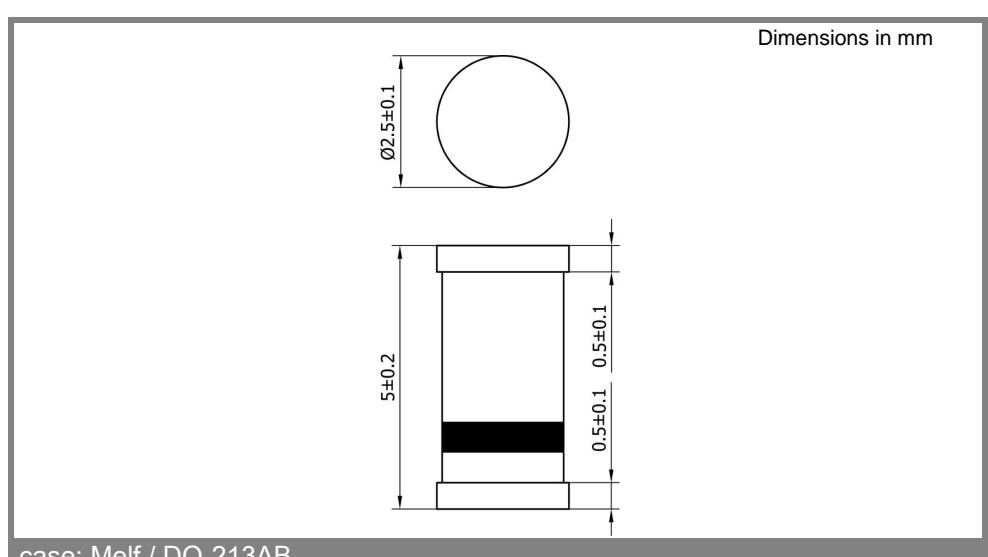
$T_c = 25^\circ\text{C}$, unless otherwise specified

Symbol	Conditions	Values	Units
I_{FAV}	Max. averaged fwd. current, R-load, $T_T = 75^\circ\text{C}$	1	A
I_{FRM}	Repetitive peak forward current $f > 15 \text{ Hz}^1)$	10	A
I_{FSM}	Peak fwd. surge current 50 Hz half sinus-wave ³⁾	40	A
I_{rt}	Rating for fusing, $t < 10 \text{ ms}^3)$	8	A ² s
R_{thA}	Max. thermal resistance junction to ambient ⁴⁾	45	K/W
R_{thT}	Max. thermal resistance junction to terminals	10	K/W
T_j	Operating junction temperature	-50...+175	°C
T_s	Storage temperature	-50...+175	°C

Characteristics

$T_c = 25^\circ\text{C}$, unless otherwise specified

Symbol	Conditions	Values	Units
I_R	Maximum leakage current, $T_j = 25^\circ\text{C}$; $V_R = V_{RRM}$ $T_j = 100^\circ\text{C}$; $V_R = V_{RRM}$	<5 <50	µA µA
C_J	Typical junction capacitance (at MHz and applied reverse voltage of V)	-	pF
Q_{rr}	Reverse recovery charge ($U_R = V$; $I_F = A$; $dI_F/dt = A/\text{ms}$)	-	µC
E_{RSM}	Non repetitive peak reverse avalanche energy ($I_R = mA$; $T_j = ^\circ\text{C}$; inductive load switched off)	-	mJ



case: Melf / DO-213AB

SM 4001...SM 4007

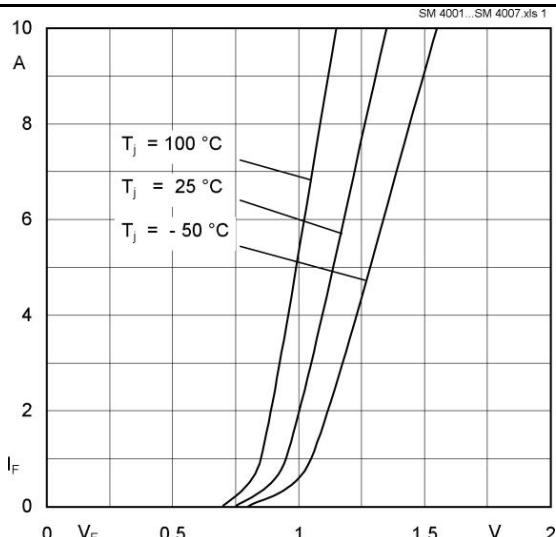


Fig. 1 Forward characteristics (typical values)

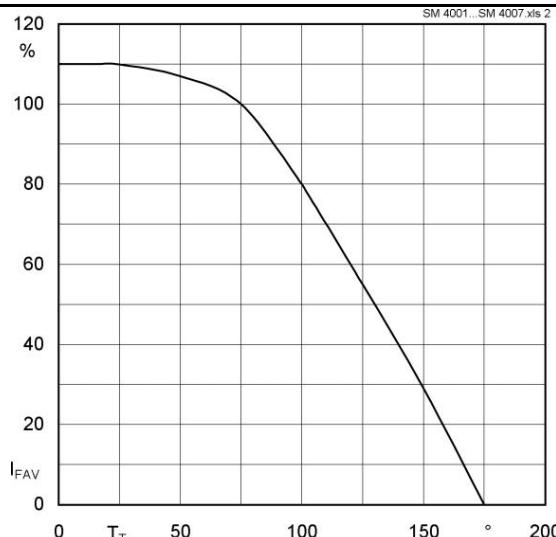


Fig. 2 Rated forward current vs. temp. of the terminals ⁴⁾